SCX microCMOS Gate Array Family Application Guide

TABLE OF CONTENTS

| 1.0 | General Description | ? |
|-------|---|--|
| 2.0 | Product Features | 2 |
| 2.0.1 | Enhanced Product Features | 2 |
| 2.1 | microCMOS Process and Circuit Personalization 3 | } |
| 2.2 | Gate Array Basic Cell 3 | 3 |
| 2.3 | Power Dissipation 3 | } |
| 2.4 | Absolute Maximum Ratings | 1 |
| 2.5 | Recommended Operating Conditions | 1 |
| 2.6 | DC Electrical Characteristics | 1 |
| 2.7 | AC Electrical Characteristics | į |
| 3.0 | Topology and Routing Resource Distribution 5 | 5 |
| | SCX6206 (600) | 5 |
| | SCX6212 (1.2k) | 5 |
| | SCX6218 (1.8k) | 5 |
| | SCX6225 (2.5k) | 5 |
| | SCX6232 (3.2k) 6 | 3 |
| | SCX6244 (4.4k) | ŝ |
| 4.0 | On-Chip Test Circuitry | 3 |
| 5.0 | Macros 6 | ŝ |
| 5.1 | Hardware Macros | 3 |
| 5.2 | Peripheral Macros 8 | 3 |
| 6.0 | Software Macros | 8 |
| 6.1 | Software Macros (User Generated) | |
| 7.0 | Packaging | 0 |
| 8.0 | Propagation Delays | 1 |
| 9.0 | Design Automation System13 | 3 |
| 9.5 | Workstation Support14 | 4 |
| 10.0 | | |
| | | |
| | | |
| | | |
| | | |
| | · | |
| 12.0 | Training and Technical Services | 2 |
| 13.0 | Technology Centers2 | 2 |
| | 2.0 2.0.1 2.2 2.3 2.4 2.5 2.6 2.7 3.0 4.0 5.0 5.1 5.2 6.0 6.1 7.0 8.0 9.0 9.5 10.0 10.1 10.2 10.3 10.4 11.0 | 2.0 Product Features 2 2.0 1 Enhanced Product Features 2 2.1 microCMOS Process and Circuit Personalization 3 2.2 Gate Array Basic Cell 3 2.3 Power Dissipation 4 2.4 Absolute Maximum Ratings 4 2.5 Recommended Operating Conditions 4 2.6 DC Electrical Characteristics 4 3.0 Topology and Routing Resource Distribution 5 SCX6206 (600) 5 SCX6212 (1.2k) 5 SCX6218 (1.8k) 5 SCX6225 (2.5k) 6 SCX6232 (3.2k) 6 SCX6232 (3.2k) 6 SCX6244 (4.4k) 6 4.0 On-Chip Test Circuitry 6 5.0 Macros 6 6.1 Software Macros 6 6.2 Peripheral Macros 6 6.1 Software Macros (User Generated) 7 7.0 Packaging 10 8.0 Propagation Delays 1 9.0 Design Exam |

61

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14 General Description

National Semiconductor's CMOS gate array Family utilizes a dual layer metal technology (microCMOS) to achieve operating speeds similar to Schottky-TTL with the inherent lower power consumption of standard CMOS integrated circuits. The SCX6200-Series Family is available in 2-micron drawn geometry with a 1.4 micron effective channel length. The range of complexity is currently from 600 to 6000 gates. The gates are arranged in cells. Each cell has the equivalent of three 2-input NAND or NOR gates. All outputs have the ability to drive 10 LSTTL loads. All inputs have high noise immunity and are protected from static discharge.

National Semiconductor supports gate array designs with a variety of user/vendor interfaces. This ranges from producing arrays from the user's schematic to accepting databases for mask generation. A large dedicated staff of gate array professionals is available to help the user determine the most efficient and cost effective way to interface on any given design.

The design automation tools include workstation or text file entry (for schematic capture), logic and timing verifiers to substantiate the actual design, fault grading analysis to gauge testability and a large selection of macros (hardware and software) to speed and simplify the design.

2.0 Product Features

- Latch-up proof, state-of-the-art 2-micron (drawn) dualmetal silicon-gate microCMOS technology
- Ultra-high performance—1 ns typical gate delays
- Available from 600 gates to 6000 gates
- CMOS power dissipation
- All inputs and I/Os protected from over-voltage and latchup
- Full design automation support
 - Schematic capture
 - Logic simulator with timing information
 - Fault grading
- Multiple power rail pin connections
- Multiple packaging options in ceramic, plastic, leaded and leadless
- Pin counts to 172
- Military performance
- Alternately sourced

996

■ Complete hardware/software macrocell libraries

- On-chip self-test capability (6.0K only)
- 100% auto-place-and-route at 90% utilization
- Design automation system supported on mainframe and workstations

2.0.1 Enhanced Product Features

The SCX6200-series gate array family is available in seven device increments from 600 to 6000 gates. The initial members of the 2-micron family consist of SCX6212, 6225 and 6260. Today it has been enhanced and expanded to include the 6244, 6232, 6218 and 6206. These enhanced devices contain several new features as follows:

- Flexible I/O Structure The I/O buffer has been enhanced to handle multiple functions including:
- Low-drive inputs compatible with TTL, CMOS or Schmitt Trigger
- High-drive (Clock Driver) inputs compatible with TTL, CMOS or Schmitt Trigger
- Output compatible with TTL and CMOS and configurable as TRI-STATE®, non TRI-STATE or Open Drain
- Outputs selectable for 1, 2 or 4 mA drive
- -- Bidirectional inputs/outputs
- Oscillator macros to drive 1, 2 or 4 mA
- Separate power supply traces for output drivers improve noise immunity

The input capacitance loading of the output drivers has also been reduced to enhance the overall circuit performance.

- Selectable Output Drive Capability The enhanced I/O structure now makes it possible to offer a variety of output drives for any given I/O location. Through implementation of I/O macro options, users can select their output drives in 1, 2 or 4 mA for each output buffer.
- Parallel I/O Buffers for High Drives By means of special I/O macros, output drive current in excess of 4 mA can be achieved by paralleling I/O buffers without losing the input functions. For example, to achieve 24 mA, six 4 mA I/O buffers need to be paralleled up; through use of the special macros, one pin is needed to implement the output which can be bidirectional while 5 pins can still be used as inputs.
- Dedicated Multiplexed D-Flip/Flops Incorporated into the internal array core is a number of dedicated multiplexed D-flip/flops. These flip/flops have been designed to achieve significant system speed improvement over a logically eqivalent macro function while minimizing silicon space to implement. They are ideal for scan path design techniques as well as registers and counters.

| Array Name | Equivalent 2-Input Gates (Note 1) | Input Cells | I/O Cells | Signal Pins | Test Pin | V _{DD} Pins | V _{SS} Pins |
|------------------|--------------------------------------|-------------|--------------|----------------|-------------|-------------------------|-------------------------|
| SCX6206 | 600 | 8 | 40 | 48 | 1 | 4 | 4 |
| SCX6212 | 1260 | 17 | 42 | 59 | 1 | 4 | 4 |
| SCX6218 | 1806 | 3 | 70 | 73 | 1 | 8 | B |
| SCX6225 | 2430 | 12 | 76 | 88 | 1 | 6 | |
| SCX6232 | 3162 | 3 | 101 | 104 | 1 | 8 | 8 |
| SCX6244 | 4380 | 3 | 110 | 113 | 1 | В | <u>R</u> |
| SCX6260 (Note 2) | 6090 | 66 | 88 | 154 | 6 | 8 | 9 |

Note 1: Input and I/O cells are not considered part of the internal cell count.

Note 2: Advanced Architecture with additional 2500 gates for on-chip self-test capability.

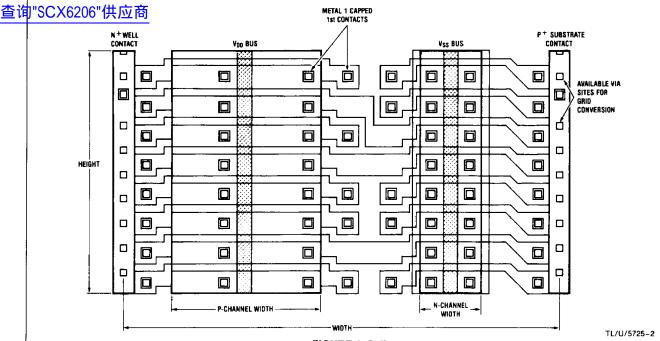


FIGURE 1. Cell

2.1 microCMOS PROCESS AND CIRCUIT **PERSONALIZATION**

The microCMOS process developed by National is based on P-type starting material, N-well technology and oxide isolation. After the basic transistors are formed (in their respective cells), two separate layers of metalization (M1 and M2) are placed on the wafers.

The processing steps and tooling requirements for all the wafers up to the metal layers are common and fixed. Circuit patterns-called "options"-are defined by the two metal layers and the VIAs. In this way, the user's design (or circuit personality) is imposed on the wafer.

All SCX gate arrays in the family use the same basic internal cell. There are eight pairs of N and P-type MOS transistors in each cell (see Figure 1). The power and ground lines (VDD and VSS buses, respectively) run up and down the cell. This cell is repeated in all four directions to form columns and rows in the core of the array. The structure of the internal core is optimized to the size of each family member.

National Semiconductor maintains an inventory of gate array wafers fabricated up to but before metalization. As the customer's options are designed and the last three patterns finalized, wafers are taken out of inventory and the fabrication process completed for the metal layers.

In this way, National Semiconductor can provide gate array users with quick turn-around cost effective designs while maintaining the quality, reliability and production control of an in-house (4 and 6-inch) wafer fab line.

2.2 GATE ARRAY BASIC CELL

Figure 1 shows the basic internal cell. The geometries are not drawn to scale and the exact topology has been modified for illustration purposes.

2.3 POWER DISSIPATION

An outstanding feature of microCMOS circuits is their low power dissipation. CMOS circuits draw electrical current for basically two reasons:

- (1) During transition from a logic "0" to a logic "1" or vice versa, there exists a finite time when the P-channel and Nchannel devices associated with the logic element are both conducting. The CMOS circuit consumes power during this transition.
- (2) When signals change state, the distributed capacitance in the circuit (and its load) need to be either charged or discharged. The electrical current required for this purpose increases power consumption.

Thus, power dissipation is dependent on operating voltage, nodal capacitance and the frequency of circuit operation. Mathematically speaking:

$$P_O = CV^2F$$

For estimation purposes, the value of:

25 μW/gate/MHz per gate equivalent can be used for elements within the array.

700 μ W/MHz/output buffer at 15 pF load or 1500 μ W/ MHz/output at 50 pF load, can be used for the output buff-

Power dissipation in a CMOS array is typically dominated by output buffers driving large capacitive loads.

Figure 2 will help in estimating power consumption in a particular design.

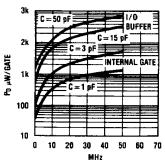


FIGURE 2. Power Consumption vs Frequency

2.4 ABSOLUTE MAXIMUM RATINGS Exceeding the following absolute maximum ratings may result in permanent damage to the device.

Supply Voltage

 $-0.5\mbox{V}$ to $7\mbox{V}$

Input or Output Voltage Storage Temperature

-0.5V to $V_{DD} + 0.5$ V -65°C to 150°C

Power Dissipation (Package Dependent) Lead Temp. (Soldering, 10 seconds)

1W 300°C

2.5 RECOMMENDED OPERATING CONDITIONS Min Max Units V_{DD}, Supply Voltage 2 6 ٧ V_I, V_O, Input or Output Voltage V_{SS} V_{DD} ٧ Io, High or Low Level Output Current 0 ± 25 mΑ I_{DD}, V_{DD} or V_{SS} Current per Pad 0 ± 50 mΑ T_A, Ambient Operating Temperature -40 + 85°C

2.6 DC ELECTRICAL CHARACTERISTICS

 $V_{DD} = 5V \pm 10\%$, min/max limits apply over recommended operating temperature range unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Max | Units |
|---------------------|--|---|-----------------------|---------------------|-------|
| V _{IH} | High Level Input Voltage | $V_{O} = 0.5V \text{ or } V_{DD} - 1V, I_{O} = 1 \mu A$ | 0.7 V _{DD} | | V |
| V _{IL} | Low Level Input Voltage | $V_{O} = 0.5 V \text{ or } V_{DD} - 1 V, I_{O} = 1 \mu A$ | | 0.3 V _{DD} | V |
| V _{OH} | High Level Output Voltage | $V_I = V_{DD}$ or GND, $I_O = 1 \mu A$ | V _{DD} -0.05 | | V |
| V _{OL} | Low Level Output Voltage | $V_I = V_{DD}$ or GND, $I_O = 1 \mu A$ | <u></u> ' | 0.05 | V |
| І он | High Level Output Current | $V_I = V_{DD}$ or GND, $V_O = V_{DD} - 0.8V$ | - 4 | | mA |
| loL | Low Level Output Current | $V_I = V_{DD}$ or GND, $V_O = 0.4V$ | 4 | | mA |
| V _{IH} TTL | Min. High Level TTL I/P Voltage (for TTL Input Option) | $V_{O} = 0.5V \text{ or } V_{DD} - 1V, I_{O} = 1 \mu A$ | 2 | | ٧ |
| V _{IL} TTL | Max. Low Level TTL I/P Voltage (for TTL Input Option) | $V_{O} = 0.5V \text{ or } V_{DD} - 1V, I_{O} = 1 \mu A$ | | 0.8 | ٧ |
| I _I | Input Current (Without Pull-Up Resistor) | $V_{I} = V_{DD}$ or GND | | ± 1 | μΑ |
| lcc | Supply Current | $V_I = V_{DD}$ or GND, $T_A = 25$ °C | <u>-</u> - | 100 | μΑ |

2.7 AC ELECTRICAL CHARACTERISTICS $V_{DD}=5V,\,T_{A}=25^{\circ}C,\,2\mu$ process.

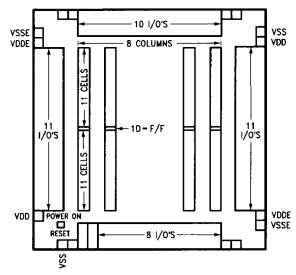
| Symbol | Parameter | Min | Max | Units |
|--------------------------------------|--|----------------------------|------------------------------|----------------|
| tplH | Output Buffer (Non-Inverting, non-TRI-STATE) $t_r = t_f = 5 \text{ ns, } 0V-5V$ $C_L = 15 \text{ pF}$ | 1.1 | 3.5 | ns |
| tpHL | | 1.2 | 4.2 | ns |
| t _{PLH} t _{PHL} | Input Buffer (TTL Type, Non-Inverting) at t _r = t _f = 5 ns, 0V-3V C _L = 1 pF | 0.75 1.10 | 2.95 3.2 | ns ns |
| t _{РLН} | Input Buffer (CMOS Type, Inverting) at $t_r = t_f = 5$ ns, $0V-5V$ $C_L = 1$ pF | 0.55 | 1.75 | ns |
| t _{РНL} | | 0.50 | 1.40 | ns |
| tPLH | Output TRI-STATE (Non-Inverting) at $t_r = t_f = 5$ ns $0V-5V$ $C_L = 50$ pF $R_L = 1$ k Ω Delays Measured at 50% Point Between Start and Target Voltage | 1.9 | 6.0 | ns |
| tPHL | | 2.5 | 6.8 | ns |
| tPZL | | 2.8 | 7.8 | ns |
| tPZH | | 1.9 | 6.0 | ns |
| tPLZ | | 7.2 | 8.3 | ns |
| tPHZ | | 7.0 | 8.2 | ns |
| tpLH tpHL tpHL tpLH | Internal 2-Input NAND at $t_r=t_f=5$ ns, 0V~5V Load Equivalent to Fan-Out of 3 and 100 mils of Interconnect As Above with $C_L=0$ pF | 0.4 0.8 0.20 0.15 | 1.55 2.30 0.75 0.55 | ns ns ns |

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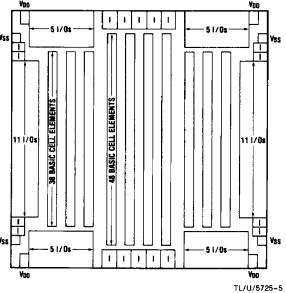
Resource Distribution

The specific topology and routing resource distribution have been tailored for each family member. Architectural considerations include the ratio of inputs and I/Os to total cell count, power consumption and package inductance to power pins (for simultaneous switching outputs) and routing resources consistant with automatic place and route software. Internal cell utilizations of greater than 85% can be expected. Individual topologies and a family summary follow.

6206 Die Structure

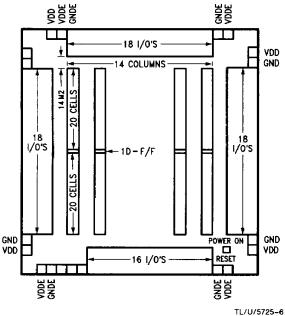


6212 Die Structure

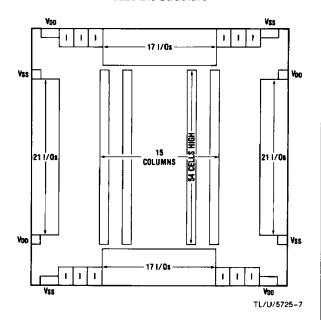


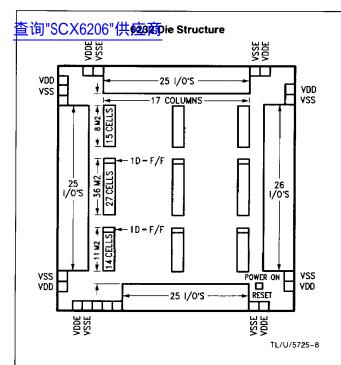
TL/U/5725-4

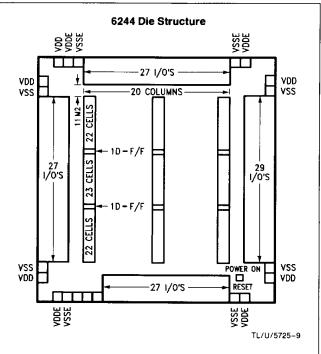
6218 Die Structure



6225 Die Structure







4.0 On-Chip Test Circuitry

Each of the SCX gate arrays is provided with dedicated onchip test circuitry. This circuitry forces all the outputs to specific states to facilitate output parametric testing. These parametric tests include leakage and current sourcing/sinking measurements on all output pins.

The on-chip test circuitry is enabled by a dedicated test mode control (TMC) pin. This pin is set aside for testing and cannot be used for any other purpose on the 6212 and 6225. However, for the enhanced devices (6244, 6232, 6218 and 6206), the extra TMC pin can be avoided by means of an internal TMC decoding circuit of the user's design. In addition, an optional internal control signal derived from the TMC pin is now available. This can be used, for example, as a set or reset control signal to the internal logic.

The self-test capability has been further expanded and enhanced on the 6k-gate 6260. It has an additional 2,500 gates dedicated to provide an on-chip maintenance system that includes chip self-test, system interconnect-test, logic analyzer, and system check-sum modes. This self-test feature on the 6260 is unique from the rest of the SCX family as well as in the industry. A low at this input will activate the on-chip test circuitry. When the on-chip test circuitry is activated, the states of all outputs are determined by two other inputs; these are TRI-STATE test control (TSTC) and data test (DT). The TSTC and DT can share input pins with the user's design. They are only active when the TMC is enabled. The TSTC input has precedence over the DT input. The TMC input is active for the following discussion.

When the TSTC input is active, all the output buffers are put into a high impedance mode. When TSTC is not active, the states of the output buffers are determined by the DT input. These two inputs can be assigned to any of the input pins.

On-Chip Test Circuitry Truth Table

| TMC | DT | TSTC | Output |
|-----|------------|------------|-----------|
| 0 | X | Active | TRI-STATE |
| 0 | Non-Active | Non-Active | 1 |
| 0 | Active | Non-Active | 0 |

Definition of Test Input States

| | Non-Inverting Macros | Inverting Macros |
|------------|-------------------------|---------------------|
| Non-Active | 0 | 1 |
| Active | 1 | 0 |

5.0 Macros

Three types of macros are available for designers to use: hardware macros, software macros (National Semiconductor standard library), and user generated software macros.

5.1 HARDWARE MACROS

The SCX family of gate arrays offers an extensive library of hardware macros (Table I). Each macro has been fully characterized and functionally proven. The designer can select those macros that most efficiently implement the design. The electrical performance of the macros is characterized at two sets of conditions: best and worst-case. Under each set of conditions, the output loading is specified at 0 pF and 1.0 pF. The 1.0 pF load is equivalent to a fan-out of 3 and includes 100 mils length of metal interconnect. A single input load is equivalent to 0.13 pF and is defined as a load factor of 1.

National Semiconductor has very tight wafer fabrication guidelines. However, process parameters still do vary from wafer-to-wafer, lot-to-lot. The electrical specifications of the macros take into account such variations.

查询"SCX6206"供应商 TABLE I. Table of Macros

| <u>(X62U6"拱/V图</u> | · · · · · · · · · · · · · · · · · · · |
|--|---------------------------------------|
| Function | Macro Name |
| GATES | T |
| Triple 2-Input NAND | C001 (S1) |
| Dual 3-Input NAND | C002 (S2) |
| Dual 2-Input NAND/AND | C003 (S3) |
| Triple 2-Input NOR | C004 (S4) |
| Dual 3-Input NOR | C005 (S5) |
| Dual 2-Input NOR/OR | C006 (S6) |
| Single 2-Input Exclusive-OR | C053 (S53) |
| 2-Input 2-Wide OR-NAND with Complement | C014 (S14) |
| 2-Input 2-Wide AND-NOR with Complement | C015 (S15) |
| Triple 4-Input NAND | C017 (D1) |
| Single 5-Input NAND (2X) | C018 (D2) |
| Triple 3-Input NAND with Complement | C019 (D3) |
| Triple 4-Input NOR | C020 (D4) |
| Single 5-Input NOR (2X) | C021 (D5) |
| Triple 3-Input NOR with Complement | C022 (D6) |
| 4-Input Exclusive-OR | C046 (T2) |
| 3-Input Exclusive-OR | C047 (D10) |
| Single 2-Input Exclusive-NOR | C048 (S21) |
| 5-Input NAND-AND | C057 (D57) |
| 5-Input NOR-OR | C058 (D58) |
| 3-Input Exclusive-NOR | C800 (D800) |
| 8-Input AND/NAND | C830 (D830) |
| 8-Input OR/NOR | C878 (D878) |
| BUFFERS | |
| Triple 2X Buffer | C007 (S7) |
| Quad Inverter | C008 (S8) |
| Dual TRI-STATE Inverting Buffer | C009 (S9) |
| Single Non-Inverting TRI-STATE Buffer | C010 (S10) |
| Schmitt Trigger | C025 (S24) |
| Quad Inverter Buffer | C043 (S20) |
| Dual Triple Inverter Buffer | C044 (S19) |
| 1-3 Buffer | C045 (S22) |
| 3-1 Buffer | C061 (S23) |
| 2-2 Buffer | C049 (S18) |
| 4-Input Exclusive-OR Buffer (2X) | C801 (T801) |
| Quad Pulldown with Common Enable | C808 (S808) |
| Quad Pulldown with 6-Input Enable Decode | C811 (D811) |
| Quad Pullup with 6-Input Enable Decode | C812 (D812) |
| Quad Pullup with Common Enable | C832 (S832) |
| <u> </u> | · · · · · · · · · · · · · · · · · · · |

| Function | Macro Name |
|--|-------------|
| LATCHES | |
| NAND R/S Latch with 2-Input NAND | C012 (S12) |
| NOR R/S Latch with 2-Input NOR | C013 (S13) |
| D-Latch with Set/Reset | C062 (D11) |
| 1-Bit Transparent D-Latch with Reset and Enable | C026 (D12) |
| Triple R/S NAND Latch | C027 (D7) |
| Triple R/S NOR Latch | C031 (D8) |
| FLIP-FLOP | |
| D Flip-Flop | C023 (D9) |
| D Flip-Flop with Set and Reset | C024 (T1) |
| D Flip-Flop with Reset and Parallel Load | C034 (Q4) |
| D Flip-Flop with Set/Reset Master Slave | C051 (T3) |
| D Flip-Flop with Set/Reset Buffered | C060 (T60) |
| D Flip-Flop with Reset (Q Output Only) | C064 (D64) |
| Multiplexed D Flip-Flop with Reset | C035 (Q35) |
| J-K Flip-Flop with Reset and Set | C037 (F37) |
| J-K Flip-Flop with Set/Reset Master Slave | C052 (Q2) |
| T Flip-Flop with Inverter Reset | C036 (Q6) |
| T Flip-Flop with Reset | C861 (Q861) |
| REGISTERS AND COUNTERS | |
| 2-Bit Serial In/Out and Parallel Out Shift Register | C039 (F1) |
| 2-Bit Serial/Parallel Shift Register | C042 (H4) |
| Universal Shift Register State | C194 (F194) |
| Up-Down Counter Stage with Parallel Load | C038 (F2) |
| 4-Bit Binary Counter Control Logic | C871 (Q871) |
| MULTIPLEXER & DEMULTIPLEXER | |
| 2-to-1 Multiplexer with Single Control Input | C056 (S56) |
| 4-to-1 TRI-STATE Multiplexer with Enable Low | C028 (T4) |
| 4-to-1 Multiplexer with Complement Output | C029 (T5) |
| 1-to-4 Decoder with Active Low Outputs and Enable Input | C033 (Q3) |
| 3-to-8 Decoder | C138 (H138) |
| 8-Channel Digital Multiplexer | C151 (H151) |
| Quad 2-Input Multiplexer | C158 (Q158) |
| Quad 2-Channel TRI-STATE Multiplexer | C257 (Q257) |

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TABLE I. Table of Macros (Continued)

| *************************************** |
|---|
| Macro Name |
| |
| C030 (T6) |
| C032 (T7) |
| C040 (H2) |
| C041 (H3) |
| |

| Function | Macro Name |
|-----------------------|---------------------|
| INPUTS AND OUTPUTS | |
| Inputs Only (36) | See I/O Macro Table |
| Outputs Only (9) | See I/O Macro Table |
| Bidirectional (72) | See I/O Macro Table |
| Oscillator Macros (3) | See I/O Macro Table |

Notes on Macro Name

Note 1: Cell Count S = 1 cell (3 gates)

Q = 4 cells (12 gates)

D = 2 cells (6 gates)

F = 5 cells (15 gates)

T = 3 cells (9 gates)

H = 6 cells (18 gates)

Note 2: The 'C000' designator is a common reference used between National Semiconductor and its alternate source for the purpose of consistency with users.

TABLE II. I/O Macro Table

| I/O Macro Type | Input Macro | Output Macro | Input Drive | | Output Drive | | | Each Capable of | | | |
|-----------------------|-------------|--------------|-------------|----|--------------|------|------|--------------------|---|-------------|-----|
| | Input Macro | Output macro | 1X | 7X | 15X | 1 mA | 2 mA | 4 mA | V | D | N |
| Input Only | TTL | • | Х | Х | Х | | | | Х | × | X |
| (36 Macros) | CMOS (INV) | | Х | Х | х | | | | X | X | X |
| | CMOS (NINV) | | Х | х | Х | | | | X | l \hat{x} | X |
| | Schmitt | | Х | Х | Х | : | | | Х | X | X |
| Output Only | | NINV | | | _ | Х | х | Х | | <u> </u> | |
| (9 Macros) | | INV | | | | Х | Х | x | | ł | |
| | ĺ | Open Drain | | | | Х | х | Х | | | |
| Bidirectional | TTL | NINV | Х | | | Х | Х | X | Х | х | X |
| (72 Macros) | CMOS (INV) | NINV | х | | | X | X | X | x | Î | x |
| | CMOS (NINV) | NINV | х | | | X | X | X | x | Î | Ϊ́χ |
| | Schmitt | NINV | Х | | | X | X | X | X | Î | x |
| | TTL | INV | Х | | | Х | X | X | X | x | X |
| | CMOS (INV) | INV | Х | | | х | X | X | X | x | X |
| | CMOS (NINV) | INV | Х | | | Х | X | $\hat{\mathbf{x}}$ | X | Î | x |
| | Schmitt | INV | Х | ĺ | | X | Х | x | x | x | x |
| Oscillator (3 Macros) | | | | | | × | Х | Х | | | |

V = Pull-Up; D = Pull-Down; N = Neither Pull-Up nor Pull-Down

5.2 PERIPHERAL MACROS

Interfacing to the SCX gate arrays is done through the peripheral buffers. There are two types of peripheral cells; input only and bi-directional I/O cells (Table II). The peripheral macros are not included in the count of internally available cells.

The buffers are located around the periphery of the die and the exact configuration is dependent on the particular family member under consideration. Reference section 3 for specific locations of input and I/O cells.

6.0 Software Macros

In addition to the pre-designed hardware macros, National Semiconductor offers a library of software macros. These software macros emulate the functions of the popular 7400 and 4000 logic families. From the designer's vantage point, these software macros are utilized as though they were hardware macros. The actual implementation of these higher order functions is handled by the design automation tools in a process that virtually expands the software macro into its hardware macro primitives.

Since the software macros reside in the design automation system, a designer may copy a software macro into his design, modify it to meet some special consideration, rename it, then reference it as a special or new software macro. This procedure is coordinated with National's Technology Centers.

National Semiconductor adds popular software macros to the existing library as required to meet user needs.

A representative list is shown in Table III. The cell count is a 'will not exceed' number, unused portions of cells are available for use in unrelated portions of the design.

6.1 SOFTWARE MACROS (USER GENERATED)

The user always has the option of generating higher order software macros. This is true regardless of where the user decides to interface with the design automation system.

At the workstation level, the user simply creates the desired function from existing hardware macros, stores the function under a unique identifier name, then recalls it as a block of logic as required.

In the text file mode of schematic capture the user defines the higher order function in terms of the basic hardware macros. These higher order (custom) functions are then 'called' in the same manner as any other software macro.

| 询"SCX6206 | | | | Software Macro | | | 6 ~II |
|-----------|-------|--------|-------|----------------|-------|----------|--------------|
| | Cell | | Cell | | Cell | . | Cell |
| Device | Count | Device | Count | Device | Count | Device | Count |
| 7400 | 1.3 | 7495 | 13.0 | 74191 | 22.0 | 74399 | 12.0 |
| 7402 | 1.3 | 7496 | 18.0 | 74192 | 23.0 | 74445 | 7.6 |
| 7403 | 1.3 | 74100 | 4.5 | 74193 | 22.0 | 74490 | 13.0 |
| 7404 | 1.5 | 74101 | 6.0 | 74194 | 20.0 | 74521 | 12.0 |
| 7405 | 1.5 | 74102 | 5.0 | 74195 | 12.0 | 74533 | 12.0 |
| 7406 | 2.0 | 74103 | 8.0 | 74196 | 23.0 | 74534 | 21.0 |
| 7407 | 6.0 | 74106 | 8.0 | 74197 | 41.0 | 74540 | 4.5 |
| 7408 | 2.0 | 74107 | 8.0 | 74198 | 21.0 | 74541 | 6.5 |
| 7409 | 2.0 | 74108 | 8.5 | 74199 | 26.0 | 74543 | 27.0 |
| 7410 | 1.5 | 74109 | 8.0 | 74237 | 12.0 | 74544 | 27.0 |
| 7410 | 2.0 | 74112 | 8.0 | 74240 | 4.5 | 74550 | 57.0 |
| | 1.5 | 74113 | 8.0 | 74241 | 6.5 | 74551 | 57.0 |
| 7412 | | | 8.5 | 74242 | 4.5 | 74563 | 12.5 |
| 7414 | 6.0 | 74114 | | 74243 | 4.5 | 74564 | 21.0 |
| 7415 | 1.5 | 74116 | 17.0 | | 8.7 | 74568 | 28.0 |
| 7416 | 2.0 | 74125 | 3.0 | 74244 | | | 26.0 |
| 7417 | 4.0 | 74126 | 3.0 | 74245 | 6.5 | 74569 | |
| 7420 | 1.3 | 74128 | 3.0 | 74251 | 13.0 | 74573 | 13.0 |
| 7421 | 1.3 | 74132 | 1.3 | 74253 | 6.5 | 74574 | 21.0 |
| 7422 | 1.3 | 74133 | 3.0 | 74256 | 19.0 | 74589 | 48.0 |
| 7425 | 3.3 | 74134 | 3.5 | 74257 | 6.0 | 74590 | 57.0 |
| 7426 | 1.33 | 74135 | 8.0 | 74258 | 3.0 | 74592 | 58.0 |
| 7427 | 1.5 | 74136 | 4.0 | 74259 | 14.0 | 74593 | 66.0 |
| 7428 | 3.3 | 74137 | 12.0 | 74260 | 4.0 | 74595 | 37.0 |
| 7430 | 2.0 | 74138 | 6.7 | 74261 | 29.0 | 74597 | 51.0 |
| 7432 | 1.3 | 74139 | 6.0 | 74266 | 4.0 | 74640 | 8.5 |
| 7433 | 3.3 | 74145 | 7.6 | 74273 | 25.0 | 74643 | 12.5 |
| 7437 | 3.3 | 74147 | 15.0 | 74279 | 2.7 | 74646 | 12.5 |
| 7438 | 3.3 | 74148 | 9.3 | 74280 | 7.0 | 74648 | 8.5 |
| | | 74149 | 15.5 | 74283 | 22.0 | 74670° | 60.0 |
| 7440 | 2.0 | | 15.0 | 74289 | 84.0 | 74688 | 11.0 |
| 7442 | 7.6 | 74150 | | 74299 | 17.0 | 744002 | 1.3 |
| 7443 | 7.6 | 74151 | 6.5 | | | 744017 | 21.0 |
| 7444 | 7.6 | 74152 | 9.0 | 74292 | 138.0 | | 44.0 |
| 7445 | 7.6 | 74153 | 6.5 | 74293 | 17.0 | 744020 | |
| 7446 | 17.0 | 74154 | 13.0 | 74294 | 74.0 | 744024 | 22.0 |
| 7447 | 17.0 | 74155 | 6.0 | 74295 | 14.0 | 744040 | 38.0 |
| 7448 | 17.0 | 74156 | 6.0 | 74298 | 13.0 | | |
| 7451 | 2.0 | 74157 | 5.0 | 74299 | 43.0 | | |
| 7458 | 2.0 | 74158 | 5.0 | 74323 | 48.0 | | |
| 7464 | 3.3 | 74159 | 13.0 | 74350 | 16.0 | | |
| 7465 | 3.3 | 74160 | 22.0 | 74354 | 30.0 | | |
| 7470 | 6.0 | 74161 | 19.5 | 74356 | 30.0 | | |
| 7471 | 6.7 | 74162 | 22.0 | 74363 | 13.0 | | |
| 7472 | 6.8 | 74163 | 20.0 | 74364 | 21.0 | | |
| 7473 | 8.0 | 74164 | 26.0 | 74365 | 5.0 | | |
| 7474 | 6.0 | 74165 | 23.0 | 74366 | 3.5 | | |
| 7474 | 4.5 | 74166 | 25.0 | 74367 | 5.0 | | |
| | | 74168 | 22.0 | 74368 | 3.5 | | |
| 7476 | 8.0 | | 20.0 | 74373 | 13.0 | | |
| 7477 | 4.5 | 74169 | | | 21.0 | | |
| 7478 | 8.0 | 74170 | 40.0 | 74374 | | | |
| 7483 | 12.0 | 74172 | 57.0 | 74375 | 4.0 | | |
| 7485 | 12.0 | 74173 | 15.0 | 74377 | 26.0 | | |
| 7486 | 4.0 | 74174 | 19.0 | 74378 | 20.0 | | |
| 7489 | 84.0 | 74175 | 19.0 | 74379 | 14.0 | | |
| 7490 | 13.0 | 74180 | 9.8 | 74386 | 4.0 | | |
| 7491 | 17.0 | 74181 | 41.7 | 74390 | 26.0 | | |
| 7492 | 13.3 | 74182 | 15.0 | 74393 | 24.0 | | |
| 7493 | 13.0 | 74189 | 84.0 | 74395 | 14.0 | | |
| 7494 | 13.0 | 74190 | 23.0 | 74398 | 12.0 | | |

查询 C Packaging 商

The SCX family of microCMOS gate arrays is offered in a very wide variety of packages. The user is provided with many choices in terms of both package type and lead count. The package types offered include ceramic pin grid arrays (PGA), leaded ceramic chip carriers (LDCC), leadless ceramic chip carriers (LCC), plastic leaded chip carriers (PCC), ceramic DIPs, and plastic DIPs.

The availability of such a large variety of packages gives the user flexibility in making the following choices:

- -Ceramic versus plastic
- —Through-hole mount versus surface mount

The specific packages offered are listed in Table IVa.

Surface mounting of multi-lead components is rapidly gaining popularity. To provide the user flexibility, National Semi-conductor offers its CMOS gate arrays in several surface mount package options: leaded and leadless ceramic chip carrier and the plastic leaded chip carrier.

Surface mounting refers to component attachment, whereby the component leads or pads rest on the surface of the PCB instead of the traditional approach of inserting the leads into through-holes which go through the board. With surface mounting there are solder pads on the PCB which align with the leads or pads on the component. The resulting solder joint forms both the mechanical and electrical connections.

The primary reason for surface mounting is to allow leads to be placed closer together than the 0.100 inch standard for DIPs with through-hole mounting. Through-hole mounting on smaller than 0.100 inch space is difficult to achieve in production and is generally avoided. The move to 0.050 inch lead spacing offered with the current generation of surface mounted components, along with a switch from a dual-in-line format to a quad format, has achieved a threefold increase in component mounting density. A need to achieve greater density is a major driving force in today's market-place.

Learning how to surface mount components to printed circuit boards requires the user to implement an assembly process not typically associated with through-hole insertion/wave soldering assembly methods.

Surface mounting involves three basic process steps:

- Application of solder or solder paste to the printed circuit board
- 2) Positioning of the component onto the printed circuit
- 3) Reflowing of the solder or solder paste.

Table IVb lists the manufacturers currently offering sockets for each of the advanced package options listed in this data sheet. A matrix of which manufacturers to contact for each socket option is provided. The listing is divided into test/burn-in and production categories. There may be some individual sockets that will cover both requirements.

TABLE IVa. Gate Array Package Options

| - Total date Array Lackage Options | | | | | | | | |
|---------------------------------------|-----------------------------|-------------|-------------|-------------|------------------|-------------|-------------|------|
| Package Type | Pins | 6206 | 6212 | 6218 | 6225 | 6232 | 6244 | 6260 |
| Plastic DIP, N | 20 28 | X X | х | х | х | | | |
| | 40 48 | X | X X | X | X | X X | X X | |
| Ceramic DIP, D (Side Braze) | 20 28 40 48 | X X X | X X X | X X X | X X X | X X | X X | |
| Plastic Leaded Chip Carrier, PCC | 28 44 68 84 124 | × | X X X | X X X | X X X | X X X | X X X | |
| Ceramic Leaded Chip Carrier, LDCC | 124 | | | | х | X | х | Х |
| Ceramic Leadless Chip Carrier, LCC | 28 44 68 84 124 | × | X X X | X X X | X X X X | X X X | X X X | x |
| Ceramic Pin Grid Array, PGA | 68 84 124 172 | | х | X | X X X | X X X | X X X | X |

| X02U0 1共7V 份 | | | | | |
|-------------------------------|--|---------------------------------|--|--|--|
| Package Type | Test/Burn-In | Production | | | |
| Ceramic Pin Grid Array | Amp, Textool, Yamaichi, Thomas & Betts | Amp, Yamaichi Thomas & Betts | | | |
| Leaded Ceramic Chip Carrier | Yamaichi | Yamaichi | | | |
| Leadless Ceramic Chip Carrier | Amp, Plastronics, Textool | Amp, Plastronics | | | |
| Plastic Chip Carrier | Textool | Amp, Burndy, Robinson/Nugent | | | |

Vendor Location and Telephone

Amp Inc. Harrisburg, PA (715) 564-0100 Textool Irving, TX (214) 259-2678

Plastronics Irving, TX (214) 258-1906 Thomas & Betts Raritan, NJ (210) 469-4000

Robinson/Nugent New Albany, IN (812) 945-0211

Yamaichi c/o Napenthe Dist. Palo Alto, CA (415) 856-9332

Burndy Norwalk, CT (203) 838-4444

8.0 Propagation Delays

Propagation delays in CMOS arrays are a function of several factors:

- Supply voltage
- Junction temperature
- Process tolerance
- Fan-out loading
- Interconnection routing
- · Input signal direction

To assist the designer in evaluating circuit performance under all operating conditions, National Semiconductor guarantees DC and AC parametrics over the full voltage and temperature range, as well as best-case and worst-case propagation delays. Process tolerance is included in the specifications.

Delays other than three for fan-out loading may be extrapolated for loads other than shown.

For example: a 2-input NAND (S1) drives six loads. What is the worst-case LO to HI delay?

From Table V

 t_{PLH} for 0 pF = 0.75 ns (0 loads)

 t_{PLH} for 1 pF = 2.40 ns (3 loads)

The delay per load = 2.40 - 0.75)/3 = 0.55 ns

Total delay = base delay (0 load) + six loads

4.05 ns = 0.75 ns + 6 (0.55 ns)

What is the delay if the power supply is maintained at 5V and junction temperature is 80°C (approximately 65°C ambient)?

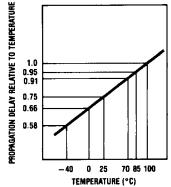


FIGURE 3. CMOS Propagation Delays as a Function of Temperature

From scaling factors (Table IV note):

Worst-case junction temperature = 100°C

New junction temperature = 80°C

Improvement factor =
$$\frac{0.3\%}{^{\circ}\text{C}}$$
 (100°C $-$ 80°C) = 6%

Worst-case voltage = 4.5V

New voltage = 5.0V

Improvement factor =
$$\frac{2\%}{0.1 \text{V}} (5.0 \text{V} - 4.5 \text{V}) = 10\%$$

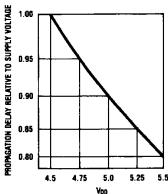
Derating factor = (1 - 0.06)(1 - 0.1) = 0.846

Total delay (scaled) = 4.05(0.846) = 3.43 ns

This form of calculation is handy for making estimates of critical paths during the initial design phase and can be used as a guide to determine estimated performance of NSC's 2μ process. The actual AC performance prediction will be provided by the design automation system after the designer has functionally verified his design in the logic simulator.

Propagation delays as a function of temperature and supply voltage are shown in *Figures 3* and 4 respectively. Utilization of these curves will speed the estimation of performance at other than specified values.

Representative macro types for the 2μ process (Table V) are presented for comparison. Reference SCX family macro library book for complete specifications.



Voo TL/U/5725-11
FIGURE 4. CMOS Propagation Delays
as a Function of Supply Voltage

TL/U/5725-10

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| Best-Case | Worst-Case |
|-----------------------|-----------------------|
| Temperature = -40°C | Temperature = 100°C |
| Supply Voltage = 5.5V | Supply Voltage = 4.5V |
| Extreme Process | Extreme Process |
| Parameters | Parameters |

TABLE V. 2μ

| | | | Best- | Case | Worst | T | |
|----------------------------|------------------------|------|------------------|------------------|------------------|------------------|------------------------|
| Symbol | Function | LF | t _{PLH} | t _{PHL} | t _{PLH} | t _{PHL} | C _{LOAD} (pF) |
| S1 | 2-NAND | 1 | 0.095 0.39 | 0.19 0.67 | 0.75 2.40 | 0.95 4.05 | 0 |
| S2 | 3-NAND | 1 | 0.09 0.37 | 0.27 0.92 | 0.95 2.65 | 1.65 5.75 | 0 1 |
| S4 | 2-NOR | 1 | 0.16 0.62 | 0.15 0.51 | 1.1 4.15 | 0.95 2.85 | 0 1 |
| S5 | 3-NOR | 1 | 0.23 0.85 | 0.16 0.52 | 1.65 6.1 | 1.13 3.05 | 0 1 |
| S7 | Clock Buffer | 2 | 0.07 0.24 | 0.13 0.33 | 0.45 1.45 | 0.55 1.65 | 0 |
| S8 | Inverter | 1 | 0.095 0.36 | 0.16 0.52 | 0.6 2.35 | 0.75 2.6 | 0 1 |
| S11 | 2-XOR | 2 | 0.11 0.54 | 0.16 0.53 | 2.6 5.8 | 2.5 5.65 | 0 |
| D9 D Flip-Flop CLK to Q | | 1 3 | 0.71 1.02 | 0.59 0.94 | 5.12 7.0 | 4.38 6.25 | 0 |
| == . | CLK to Q _B | | 0.35 0.64 | 0.54 0.98 | 2.38 5.37 | 3.3 6.62 | 0 1 |
| S9 | TRI-STATE Inverter | 1 | 0.18 0.60 | 0.18 0.70 | 1.2 4.25 | 1.35 4.15 | 0 1 |
| S10 | TRI-STATE Buffer | 2 | 0.30 0.53 | 0.27 0.53 | 1.9 3.4 | 1.8 3.4 | 0 |
| l ₄ | Inverting Input Buffer | CMOS | 0.23 0.45 | 0.19 0.39 | 0.85 2.30 | 0.70 1.80 | 0 1 |
| l ₁ | Input Buffer | TTL | 0.33 0.60 | 0.39 0.78 | 2.0 3.70 | 2.45 4.80 | 0 1 |
| l ₆ | Short Circuit Input | CMOS | 0.04 0.15 | 0.04 0.15 | 0.07 0.50 | 0.07 0.50 | 0 1 |
| 101 | Input | TTL | 0.33 0.60 | 0.39 0.78 | 2.0 3.7 | 2.45 4.8 | 0 |
| | Output* | 7 | 0.62 1.15 | 0.78 1.55 | 4.4 7.0 | 5.75 9.75 | 15 50 |
| IO ₂ | Input (Inverting) | CMOS | 0.23 0.45 | 0.19 0.39 | 0.85 2.30 | 0.70 1.80 | 0 1 |
| ··· | Output* | 7 | 0.62 1.15 | 0.78 1.55 | 4.40 7.0 | 5.75 9.75 | 15 50 |
| IO ₃ | Short Circuit Input | CMOS | 0.04 0.15 | 0.04 0.15 | 0.07 0.50 | 0.07 0.50 | 0 1 |
| | Output* | | 0.62 1.15 | 0.78 1.55 | 4.40 7.0 | 5.75 9.75 | 15 50 |
| IO₄ | Output | 7 | 0.65 1.17 | 0.63 1.45 | 4.75 8.25 | 4.5 8.25 | 15 50 |

Note: All delays in nanoseconds. *TRI-STATE active mode. $t_{\text{f}}=t_{\text{f}}=2.5$ ns for 2-micron. Voltage Derate = 2.0%/100 mV from 4.5V. Temperature Derate = 0.3%/°C from 100°C. LF = Load Factor. 1LF = 0.13 pF.

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查询"SQX62Destgnn Automation System

The design automation system offers the end user a variety of interface points and techniques.

Figure 6 shows the standard gate array development flow and responsibilities. Alternative flows are available and are presented in Section 11.

The standard flow consists of four major quadrants. They are the user's site, user's responsibilities, National Semiconductor's technology center, National Semiconductor's responsibility. These represent the 'where' and 'who' aspects of task responsibility and location.

User Site

Logic design and definition are the user's responsibility and are completed at his/her site.

The design file consists of the netlist (wiring diagram) and the test vectors (pattern file). Each can be generated in a text file or as the output from a 'workstation'. The syntax of these files is in the 'hardware design language'.

The evaluation and acceptance of the completed prototypes are done by the user at his/her facilities. National Semiconductor offers technical assistance if necessary.

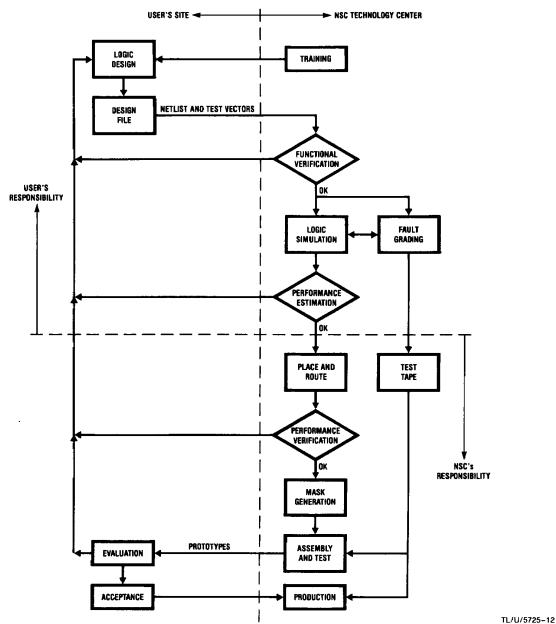


FIGURE 6. Standard Gate Array Development Process and Responsibilities

Aletional Semiconductor Technology Center

Training includes actual interaction with the design automation system and, depending on the level of user experience, requires from three to five days to complete. All of the considerations necessary for the successful completion of the design are covered during the training. Topics such as, hardware (i.e., speed, power, pinouts) and software considerations (i.e., logic simulation, fault grading, critical path analysis) are tailored to meet the user's needs. Training is provided at the closest technology center. Contact the local sales representative for the location nearest you.

Functional verification of the logic is accomplished by submitting the netlist and pattern files to the logic simulator. The simulator will predict the output results of the specified logic for the applied vectors. The designer can then determine if the specified logic meets the design objectives. Simulation under actual 'loaded' conditions occurs after functional verification and fault grading. Functional verification is the responsibility of the user.

Fault grading is a measure of the ability of the supplied vectors to detect induced logic errors (i.e., on-chip shorts). The vectors supplied eventually become the functional portion of the final production test tape. It is important that the fault grading figure of merit reach 85%. Fault grading is the responsibility of the user.

Performance estimation is the prediction that the logic simulator makes by considering actual macro loading and a projection of the interconnect lengths. This projection is based on an algorithm which relates fan-out to probable trace length. Performance estimation is the responsibility of the user.

Place and route are the actual implementation of the user's design file. Two pieces of design automation software are used to complete the routing.

Automatic place and route software completes the majority of interconnects and in most cases completes the entire array.

Interactive graphics software is used to complete any unrouted interconnects.

Place and route are the responsibility of National Semiconductor.

Performance verification is the rerunning of the 'performance estimation' software with the actual cell placements and associated trace lengths. Performance verification is the responsibility of the user.

Mask generation, wafer fab, assembly and test are completed by National Semiconductor.

Prototype evaluation and acceptance are the responsibility of the user.

National Semiconductor has a large staff of applications and consulting engineers available to assist users at any point in the array development process.

9.5 WORKSTATION SUPPORT

The above capabilities, specifically the front-end design functions (such as schematic capture, netlist entry, logic simulation and timing estimation), are also available on the Valid, Daisy, and Mentor workstations. Such capabilities will be extended to other popular CAE design stations such as CAE Systems and the IBM PC.

To allow workstation users to properly interface with the SCX-series gate arrays, National provides a workstation software design kit. It consists of a set of floppy discs containing the logic symbols of all the macros, a netlist extractor and model timing data for pre-layout simulation and timing estimation. This design kit is developed, distributed, maintained and updated solely by National.

Some of the more time-consuming tasks such as fault grading, auto-place-and-route and post-layout logic verification are performed on the mainframe computer. A typical design flow between the workstation and mainframe is illustrated in *Figure 7*. Generally, there are three design paths as follows:

- Path A—schematic capture on user's workstation; then transfer of unsimulated design files (netlist and test vectors) to NSC's mainframe for logic simulation, fault grading and place-and-route.
- Path B—schematic capture, logic simulation and timing verification on user's workstation; then transfer of simulated design files to NSC's mainframe for resimulation (one pass), fault grading and place-and-route.
- Path C—schematic capture, logic simulation, timing verification and place-and-route on user's workstation; then transfer of database file to NSC's mainframe for resimulation (one pass), fault grading and PG tape generation. (This is a future capability.)

查询"SCX6206"供应商

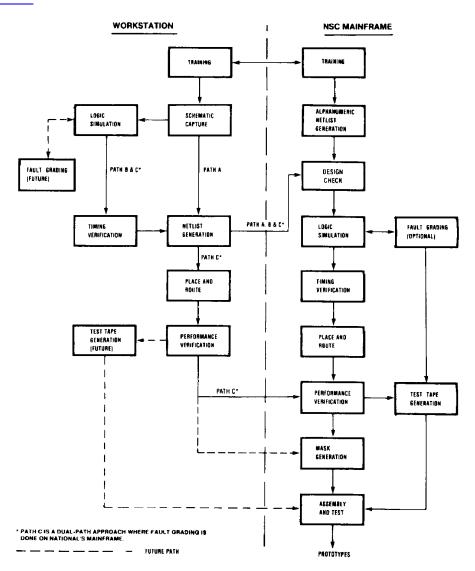


FIGURE 7. National's Workstation-to-Mainframe Semi-Custom Design Flow

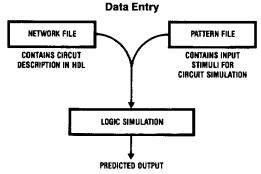
查询0.30 Design 在xemple

The two most popular ways of interfacing to the design automation system are 1) alphanumeric text entry and 2) workstation output. A different example will be given for each. In either case the design automation system requires two basics files to operate.

Network (File): The network file is the 'wiring diagram' of the design. It represents how the array is to be 'wired'. More specifically, it is the manner in which the hardware macros are interconnected. The syntax of the network file is specified by a hardware design language (HDL).

Pattern (File): The pattern file represents the stimuli or sequence of signals used to exercise the design specified by the network file. The pattern file ultimately becomes the functional portion of the final test tape used to screen production devices.

The logic simulator operates on the network and pattern files and predicts the logic output as a function of the pattern file.



TL/U/5725-13

The simulator has two modes of operation. The first mode is used to verify the logical integrity of the design. The second mode considers capacitive circuit loading and anticipated wire lengths. The result of the second mode is the performance that can be expected after the circuit has been placed and routed.

The basic form of a network file is as follows:

\$NETWORK (*BEGIN A NETWORK FILE*)
\$ INP INA INB ETC. (*LIST ALL INPUT NAMES*)

\$ OUT OUTA OUTB ETC. (*LIST ALL OUTPUT NAMES*)

•

MACRO CALLS

(*SPECIFY MACROS AND INTERCONNECTS*)

•

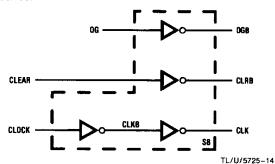
* COMM

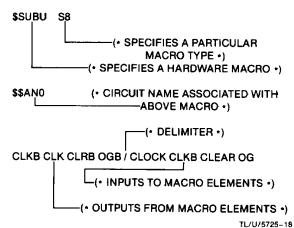
COMMENTS (*MAKE COMMENTS*)

•

•

The macro call syntax for the following circuit fragment is as specified.





If the designer were using the alphanumeric text mode of data entry, each unique macro and macro type would be specified in the above manner until the entire network had been specified.

In the workstation mode of schematic capture the designer would call and name each desired macro, then graphically interconnect each macro in the required fashion. The workstation would then 'compile' the schematic into the network

查询"SOX6PENGT (MODE)商 INB -INC -IND -COND -ID1 ·

FIGURE 8. The Design of a Four-Bit Latch with TRI-STATE Output is Presented.

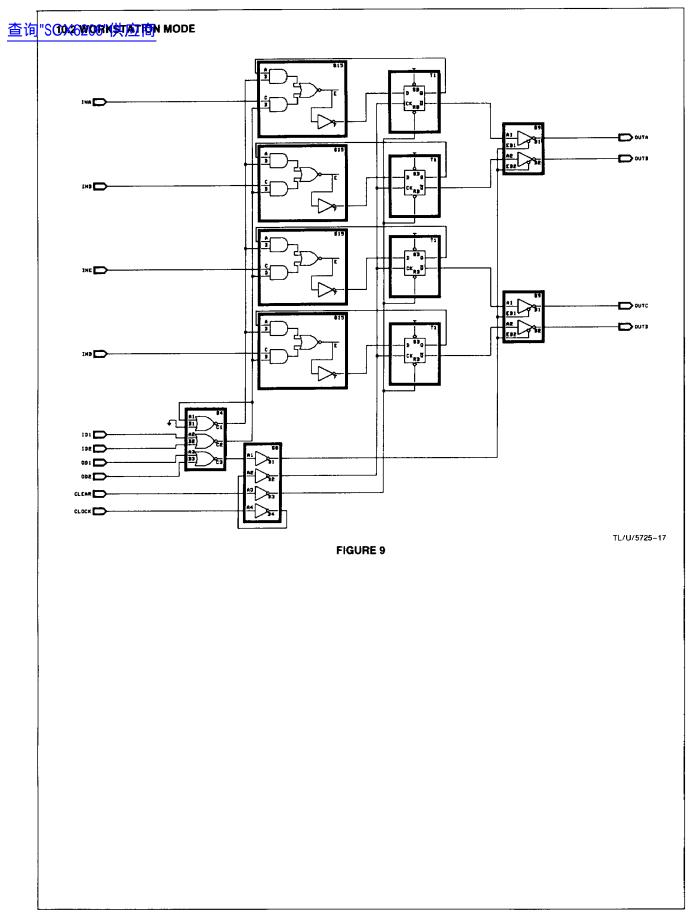
102 001 002

CLEAR -

CLOCK

TL/U/5725-16

\$\$********* \$NETWORK \$INPUT INA INB INC ID1 ID2 OD1 OD2 CLOCK CLEAR \$OUTPUT OUTA OUTB OUTC OUTD \$\$★ DM74173 MACRO \$SUBU S8 \$\$AN0 CLKB CLK CLRB OGB / CLOCK CLKB CLEAR OG \$SUBU \$4 \$\$AN1 IG IGB OG / ID1 ID2 IG CON0 OD1 OD2 \$SUBU S15 \$\$AN2 DAB DA / INA IG IGB QA \$SUBU S15 \$\$AN3 DBB DB / INB IG IGB QB \$SUBU S15 \$\$AN4 DCB DC / INC IG IGB QC \$SUBU / S15 \$\$AN5 DDB DD / IND IG IGB QD \$SUBU T1 \$\$AN6 QA QAB / CON1 DA CLK CLRB \$SUBU T1 \$\$AN7 QB QBB / CON1 DB CLK CLRB \$SUBU T1 \$\$AN8 QC QCB / CON1 DC CLK CLRB \$SUBU T1 \$\$AN9 QD QDB / CON1 DD CLK CLRB \$SUBU S9 \$\$AN10 OUTA OUTB / QAB OGB QBB OGB \$SUBU S9 \$\$AN11 OUTC OUTD / QCB OGB QDB OGB \$\$******



.. ... I

```
Listing 2
查<u>询"</u>$CX6206"供应商
 $INPUT CLEAR CLOCK ID1 ID2 INA INB INC IND OD1 OD2
 $OUTPUT OUTA OUTB OUTC OUTD
 $$*
 $SUBU S4
 $$XCMP 1
 XSIG29 XSIG27 XSIG18 / XSIG27 GND ID1 ID2 OD1 OD2
 $$*
 $SUBU T1
 $$XCMP 10
 XSIG33 XSIG41 / VCC XSIG34 XSIG20 XSIG21
 $SUBU S9
 $$XCMP 11
 OUTA OUTB / XSIG41 XSIG22 XSIG40 XSIG22
 $$*
 $SUBU S9
 $$XCMP 12
 OUTC OUTD / XSIG39 XSIG22 XSIG38 XSIG22
 $$★
 $SUBU S8
 $$XCMP 2
 XSIG22 XSIG20 XSIG21 XSIG19 / XSIG18 XSIG19 CLEAR CLOCK
 $SUBU S15
 $$XCMP 3
 OPEN-1 XSIG37 / XSIG30 XSIG29 IND XSIG27
 $$*
 $SUBU S15
 $$XCMP 4
 OPEN-2 XSIG36 / XSIG31 XSIG29 INC XSIG27
 $$*
 $SUBU S15
 $$XCMP 5
 OPEN-3 XSIG35 / XSIG32 XSIG29 INB XSIG27
 $$*
 $SUBU S15
 $$XCMP 6
OPEN-4 XSIG34 / XSIG33 XSIG29 INA XSIG27
$$ *
$SUBU T1
$$XCMP 7
XSIG30 XSIG38 / VCC XSIG37 XSIG20 XSIG21
$$*
$SUBU T1
$$XCMP 8
XSIG31 XSIG39 / VCC XSIG36 XSIG20 XSIG21
$$*
$SUBU T1
$$XCMP 9
XSIG32 XSIG40 / VCC XSIG35 XSIG20 XSIG21
$$ *
```

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```
$CYCLE = 1000 1000 REPRESENTS THE NUMBER OF INTERVALS PER CYCLE 1 INTERVAL = 100 PICOSECONDS
$$*****
$$★ PATTERN FILE CODING FOLLOWS
$$****
$$★ PATTERN FILE FOR TESTING DM74173
$$★ TEST SHOULD SWEEP 16 CYCLES
    CLEAR HI 1-2
    INA HI 1 3 5 7 11-12
    INB HI 1 3 5 7 11-12
    INC HI 1 3 5 7 11-12
    IND HI 1 3 5 7 11-12 INPUT SIGNALS USED TO SIMULATE THE NETWORK
    ID1 HI 1 3 5-6
    ID2 LO 1 3 7-8
   ∫ OD1 HI 5-6 13-14
   OD2 HI 7-8 15-16
    CLOCK LO RPT (01: 1-16) SINGLE CLOCK REPEATING 01 THROUGH CYCLE 16
   - CIRCUIT INPUTS HI AT SPECIFIED CYCLE, LOW AT ALL OTHER CYCLES
   - CIRCUIT INPUT LO AT SPECIFIED CYCLE, HI AT ALL OTHER CYCLES
                                                                               TL/U/5725-19
```

10.4 SIMULATOR OUTPUT

| | INPUTS BY P | | SPEC ERN F | OUTPUTS AS SPECIFIED BY PATTERN FILE | | |
|---|----------------|-----|---------------|--------------------------------------|---|------|
| | 1111 | 11 | 00 | С | S | 0000 |
| | NNNN | DD | DD | Ĺ | Ĺ | UUUU |
| | ABCD | 12 | 12 | Ē | ō | TTTT |
| | | . – | . – | Ā | Č | ABCD |
| | | | | R | ĸ | |
| 1 | 1111 | 10 | 00 | 1 | 0 | XXXX |
| **157 | 1111 | 10 | 00 | 1 | 0 | 0000 |
| 2 | 0000 | 0 1 | 00 | 1 | 1 | 0000 |
| 3 | 1111 | 10 | 00 | 0 | 0 | 0000 |
| 4 | 0000 | 0 1 | 00 | 0 | 1 | 0000 |
| 5 | 1111 | 11 | 10 | 0 | 0 | 0000 |
| **134 | 1111 | 11 | 10 | 0 | 0 | ZZZZ |
| 6 | 0000 | 11 | 10 | 0 | 1 | ZZZZ |
| 7 | 1111 | 00 | 0 1 | 0 | 0 | ZZZZ |
| 8 | 0000 | 00 | 0 1 | 0 | 1 | ZZZZ |
| 9 | 0000 | 0 1 | 00 | 0 | 0 | ZZZZ |
| **140 | 0000 | 0 1 | 00 | 0 | 0 | 1111 |
| 10 | 0000 | 0 1 | 00 | 0 | 1 | 1111 |
| 11 | 1111 | 0 1 | 00 | 0 | 0 | 1111 |
| 12 | 1111 | 0 1 | 00 | 0 | 1 | 1111 |
| 13 | 0000 | 0 1 | 10 | 0 | 0 | 1111 |
| **129 | 0000 | 0 1 | 10 | 0 | 0 | ZZZZ |
| 14 | 0000 | 0 1 | 10 | 0 | 1 | ZZZZ |
| 15 | 0000 | 0 1 | 0 1 | 0 | 0 | ZZZZ |
| 16 | 0000 | 01 | 01 | 0 | 1 | ZZZZ |
| LSEQUENTIAL NUMBERS REPRESENT TIME CYCLES | | | | | | |

ZZZZ = HIGH IMPEDANCE STATE

1111 = HIGH STATE

0000 = LOW STATE

^{**}Intermittent numbers represent settling time in hundred-picoseconds that occur between time cycles.

油川のAitechは1立商Interfaces

Flexibility in the design automation system allows a variety of user/vendor interfaces. Options include:

- User supplies schematic, timing diagrams and parametric specifications. National Semiconductor implements the array (Turn-Key design).
- · User 'captures' the design at his facility or at a National Semiconductor technology center. National Semiconductor supports a wide range of communication protocols for interfacing to industrial (mainframe) or personal computers. These are available with or without error control and communication rates of 300 to 9600 baud.
- · User follows basic array development flow specified in Figure 6.
- · User generates logic simulator compatible files from his workstation. Completes the array using National Semiconductor's design automation system.
- · User generates compatible design files and logic verification in his/her simulator, then interfaces to design automation system at either fault grading, performance estimation, or 'place and route'.
- User supplies completed design files from National Semiconductor's alternate source, effectively entering design automation system just prior to digitizing.
- · User provides all design files necessary for mask generation, essentially a 'customer owned tooling' (COT) approach.

12.0 Training and Technical Services

To facilitate users to design with National's CMOS gate arrays, training is offered on a regular basis at National's worldwide technology centers. At the new Santa Clara training/design center, multiple workstations are used to complement the basic training. Additional workstations located in private offices are also available for customers to enter, capture and verify their designs. As part of the technical services, experienced design consultants from National will be available at the training/design center to provide on-thespot engineering assistance.

The training, workstation design kit and other technical services are provided by National's Training, Layout, Consulting (TLC) Group. Overall technical customer-support services include the following:

- Customer training
- Technical documentation
- Design assistance

- Simulation support
- Workstation support
- Turnkey design
- Place-and-Route implementation
- · Mainframe software qualification
- Workstation software qualification

For any technical assistance, contact National's Applications Group at (408) 721-4614.

13.0 Technology Centers

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SCX microCMOS Gate Array Family Application Gu

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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